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High electron mobility, quantum Hall effect and anomalous optical response in atomically thin InSe

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| 876 | High-Performance InSe Transistors with Ohmic Contact Enabled by Nonrectifying Barrier-Type Indium Electrodes. | | |
| 875 | Electronic Structure of In ₃ Se ₄ Electron Transport Layer for Chalcogenide/p-Si Heterojunction Solar Cells. | | |
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